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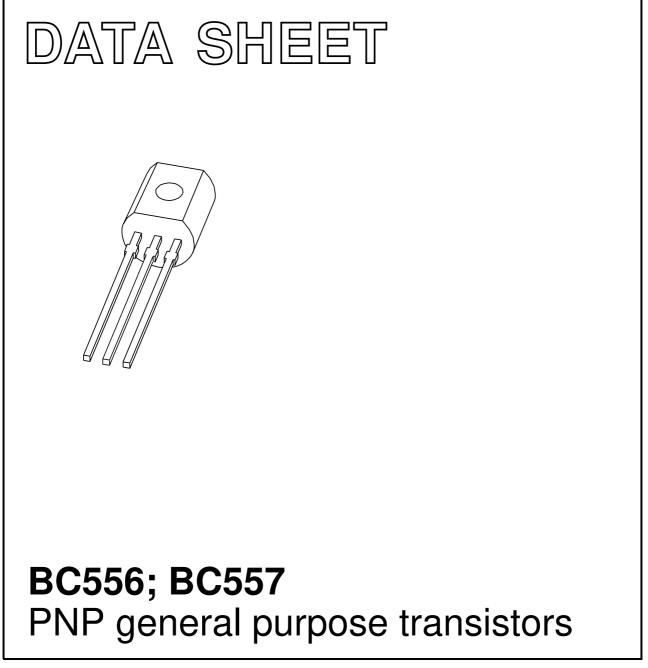


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DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1999 Apr 15 2004 Oct 11



FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 65 V).

APPLICATIONS

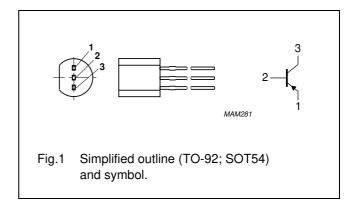
• General purpose switching and amplification.

DESCRIPTION

PNP transistor in a TO-92; SOT54 plastic package. NPN complements: BC546 and BC547.

PINNING

PIN	DESCRIPTION	
1	emitter	
2	base	
3	collector	



ORDERING INFORMATION

TYPE NUMBER	PACKAGE			
ITFE NOWBEN	NAME	DESCRIPTION	VERSION	
BC556	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54	
BC557				

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	BC556		-	-80	V
	BC557		-	-50	V
V _{CEO}	collector-emitter voltage	open base			
	BC556		-	-65	V
	BC557		-	-45	V
V _{EBO}	emitter-base voltage	open collector	-	-5	V
I _C	collector current (DC)		_	-100	mA
I _{CM}	peak collector current		-	-200	mA
I _{BM}	peak base current		-	-200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	-	500	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

BC556; BC557

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	250	K/W	

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

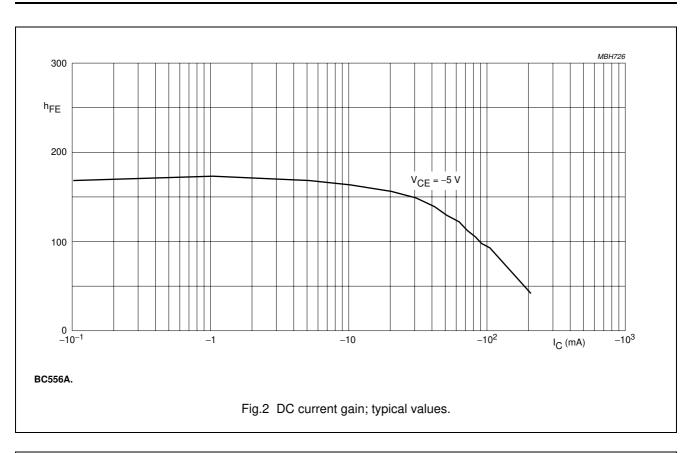
 T_{amb} = 25 °C unless otherwise specified.

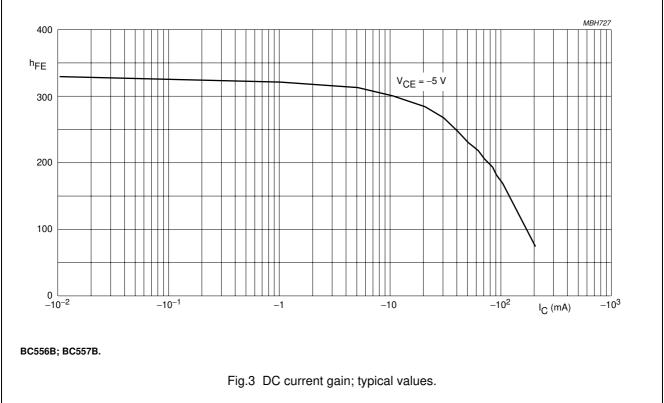
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = -30 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	-1	-15	nA
		$V_{CB} = -30 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \text{ T}_{j} = 150 ^{\circ}\text{C}$	_	_	-4	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ V}$	_	_	-100	nA
h _{FE}	DC current gain	$I_{C} = -2 \text{ mA}; V_{CE} = -5 \text{ V};$				
	BC556	see Figs 2, 3 and 4	125	-	475	
	BC557		125	-	800	
	BC556A		125	-	250	
	BC556B; BC557B		220	-	475	
	BC557C		420	-	800	
OLSal	collector-emitter saturation voltage	$I_{C} = -10 \text{ mA}; I_{B} = -0.5 \text{ mA}$	_	-60	-300	mV
		$I_{\rm C} = -100 \text{ mA}; I_{\rm B} = -5 \text{ mA}$	-	-180	-650	mV
V _{BEsat}	base-emitter saturation voltage	$I_{C} = -10 \text{ mA}; I_{B} = -0.5 \text{ mA}; \text{ note } 1$	-	-750	-	mV
		$I_{C} = -100 \text{ mA}; I_{B} = -5 \text{ mA}; \text{ note } 1$	-	-930	-	mV
V_{BE}	base-emitter voltage	$V_{CE} = -5 \text{ V}; I_C = -2 \text{ mA}; \text{ note } 2$	-600	-650	-750	mV
		$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}; \text{ note } 2$	-	-	-820	mV
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$	-	3	-	pF
Ce	emitter capacitance	$V_{EB} = -0.5 \text{ V}; I_C = i_c = 0 \text{ A}; f = 1 \text{ MHz}$	_	10	-	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; I_C = -10 \text{ mA}; f = 100 \text{ MHz}$	100	_	-	MHz
F	noise figure	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -200 \mu\text{A}; \text{ R}_{S} = 2 k\Omega;$ f = 1 kHz; B = 200 Hz	_	2	10	dB

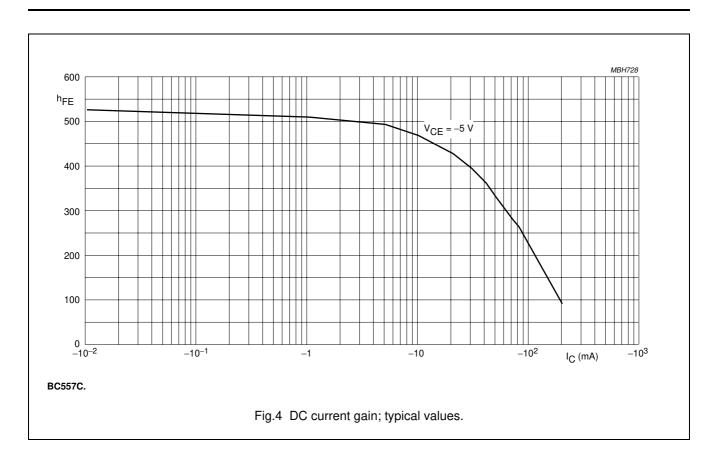
Notes

1. V_{BEsat} decreases by about -1.7 mV/K with increasing temperature.

2. V_{BE} decreases by about -2 mV/K with increasing temperature.



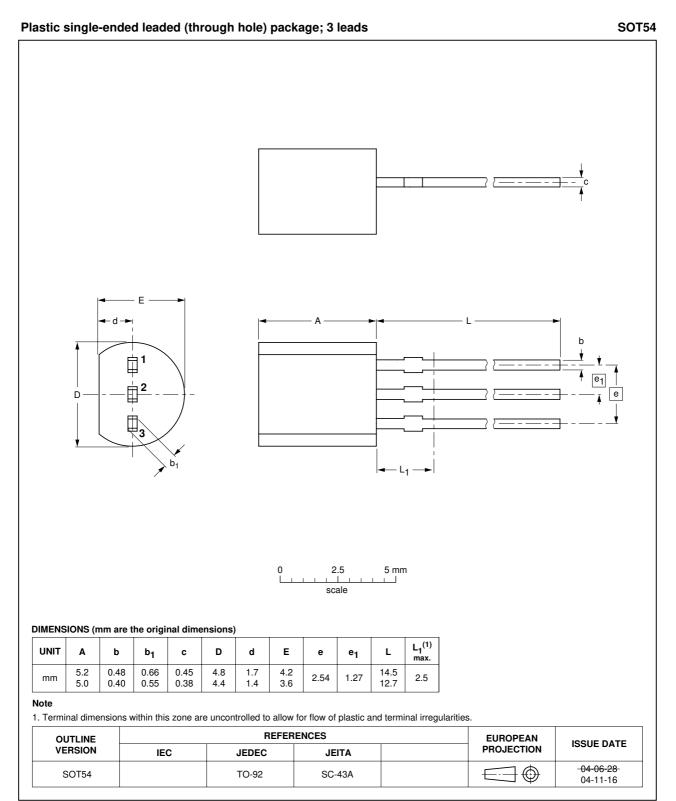




Product data sheet

PNP general purpose transistors

PACKAGE OUTLINE



BC556; BC557

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Customer notification

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Contact information

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